

MBRF3080CT

Green Products

Technical Data Data Sheet N1109, Rev. A

MBRF3080CT SCHOTTKY RECTIFIER

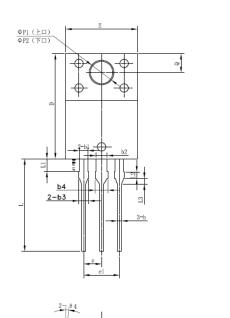
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

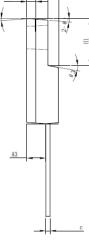
- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals: pure tin plated, solderable per MIL-STD-750, Method 2026
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

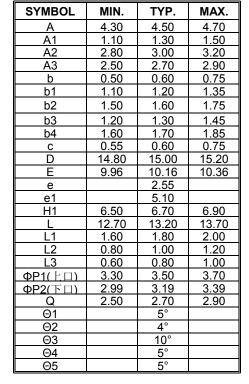
Mechanical Dimensions (In mm):



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2-05





ITO-220AB

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •



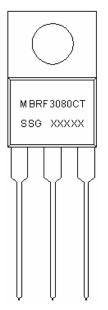


Center Tap



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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

| _ | | |
|------------|------------------------|--------------|
| Device | Package | Shipping |
| MBRF3080CT | ITO-220AB (Pb-Free) | 50pcs / tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|--|------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 80 | V |
| Average Rectified Forward Current (per device) | I _{F (AV)} | 50% duty cycle @T _C =100°C, rectangular wave form | 30 | А |
| Peak One Cycle Non-Repetitive Surge Current (per leg) | I _{FSM} | 8.3 ms, half Sine pulse | 220 | А |

China - Germany - Korea - Singapore - United States

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Where XXXXX is YYWWL

| MBR | = Device Type |
|-----|-------------------------|
| F | = Package type |
| 30 | = Forward Current (30A) |
| 80 | = Reverse Voltage (80V) |
| СТ | = Configuration |
| SSG | = SSG |
| ΥY | = Year |
| WW | = Week |
| L | = Lot Number |
| | |



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Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|-------------------------------------|-----------------|---|------|-------|-------|
| Forward Voltage Drop (per leg) * | V _{F1} | @ 15 A, Pulse, T _J = 25 °C | 0.60 | 0.745 | V |
| | V _{F2} | @ 15 A, Pulse, T _J = 125 °C | 0.58 | 0.625 | V |
| Reverse Current (per leg) * | I _{R1} | @V _R = rated V _R T _J = 25 °C | 0.30 | 1.0 | mA |
| | I _{R2} | @V _R = rated V _R T _J = 125 °C | 15 | 25 | mA |

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

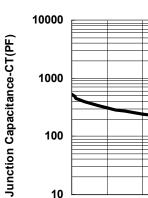
| Characteristics | Symbol | Condition | Specification | Units |
|--|------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Case | R _{θJC} | DC operation | 2.0 | °C/W |
| Approximate Weight | wt | - | 2 | g |
| Case Style | ITO-220AB | | | |



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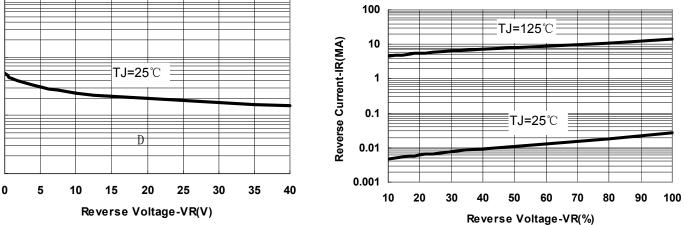




Fig.2-Typical Reverse Characteristics

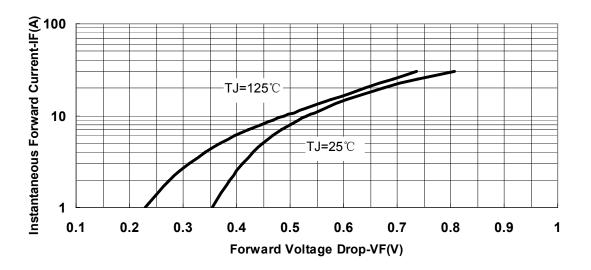


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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